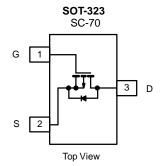
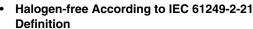


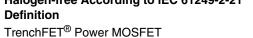
BSS84AKW-VB Datasheet P-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	$I_{DS}(V) \qquad R_{DS(on)}(\Omega)$		I _D (mA)			
- 60	4 at V _{GS} = - 10 V	- 1 to - 3	- 135			



FEATURES





- High-Side Switching
- Low On-Resistance: 4 $\,\Omega$
- Low Threshold: 2 V (typ.)
- Fast Swtiching Speed: 20 ns (typ.)
- Low Input Capacitance: 20 pF (typ.)
- Compliant to RoHS Directive 2002/95/EC



APPLICATIONS

- Drivers: Relays, Solenoids, Lamps, Hammers, Display, Memories, Transistors, etc.
- **Battery Operated Systems**
- **Power Supply Converter Circuits**
- Solid-State Relays

BENEFITS

- · Ease in Driving Switches
- · Low Offset (Error) Voltage
- Low-Voltage Operation
- **High-Speed Circuits**
- Easily Driven without Buffer

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted					
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	- 60	.,	
Gate-Source Voltage		V _{GS}	± 20	V	
0 11	T _A = 25 °C	- I _D	- 135	mA	
Continuous Drain Current ^a	T _A = 100 °C		- 105		
Pulsed Drain Current ^b		I _{DM}	- 800		
Developed and the standards	T _A = 25 °C	P _D	350	mW	
Power Dissipation ^a	T _A = 100 °C	' D	140	mv	
Maximum Junction-to-Ambient ^a		R _{thJA}	350	°C/W	
Operating Junction and Storage Temperature Range		T _{J,} T _{stg}	- 55 to 150	°C	

- a. Surface mounted on FR4 board.
- b. Pulse width limited by maximum junction temperature.

服务热线:400-655-8788

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			Limits				
Parameter	Symbol	Test Conditions	Min.	Typ. ^a	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_{D} = -10 \mu\text{A}$	- 60			V	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 1		- 3	ľ	
	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 10 μA		
Cata Bady Laakaga		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 10 \text{ V}$			± 200	nA	
Gate-Body Leakage		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 10 \text{ V}, T_{J} = 85 ^{\circ}\text{C}$			± 500		
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 5 \text{ V}$			± 100		
Zoro Coto Voltago Droin Current	,	V _{DS} = - 60 V, V _{GS} = 0 V			- 25		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 60 V, V _{GS} = 0 V, T _J = 85 °C			- 250		
On-State Drain Current ^a	I _{D(on)}	V _{GS} = - 10 V, V _{DS} = - 4.5 V	- 50			-m A	
On-State Drain Current		V _{GS} = - 10 V, V _{DS} = - 10 V	- 600			mA	
	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 25 mA	5				
Drain-Source On-Resistance ^a		V _{GS} = - 10 V, I _D = - 100 mA		4		Ω	
		V _{GS} = - 10 V, I _D = - 100 mA, T _J =125 °C			9		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 100 mA 80			mS		
Diode Forward Voltage	V _{SD}	I _S = - 100 mA, V _{GS} = 0 V			- 1.4	٧	
Dynamic	<u> </u>						
Total Gate Charge	Qg			1.7		nC	
Gate-Source Charge	Q _{gs}	$V_{DS} = -30 \text{ V}, V_{GS} = -15 \text{ V}$ $I_{D} \cong -100 \text{ mA}$		0.26			
Gate-Drain Charge	Q _{gd}	1D = 100 m/r		0.46		1	
Input Capacitance	C _{iss}			23		pF	
Output Capacitance	C _{oss}	$V_{DS} = -25 \text{ V}, V_{GS} = 0 \text{ V}$ f = 1 MHz		10			
Reverse Transfer Capacitance	C _{rss}	1 - 1 1/1/12		5			
Switching ^b							
Turn-On Time	t _{d(on)}	$V_{DD} = -25 \text{ V}, R_{L} = 150 \Omega$		20		T	
Turn-Off Time	t _{d(off)}	$I_D \cong$ - 200 mA, $V_{GEN} = -10 \text{ V}$, $R_g = 10 \Omega$	2 35			ns	

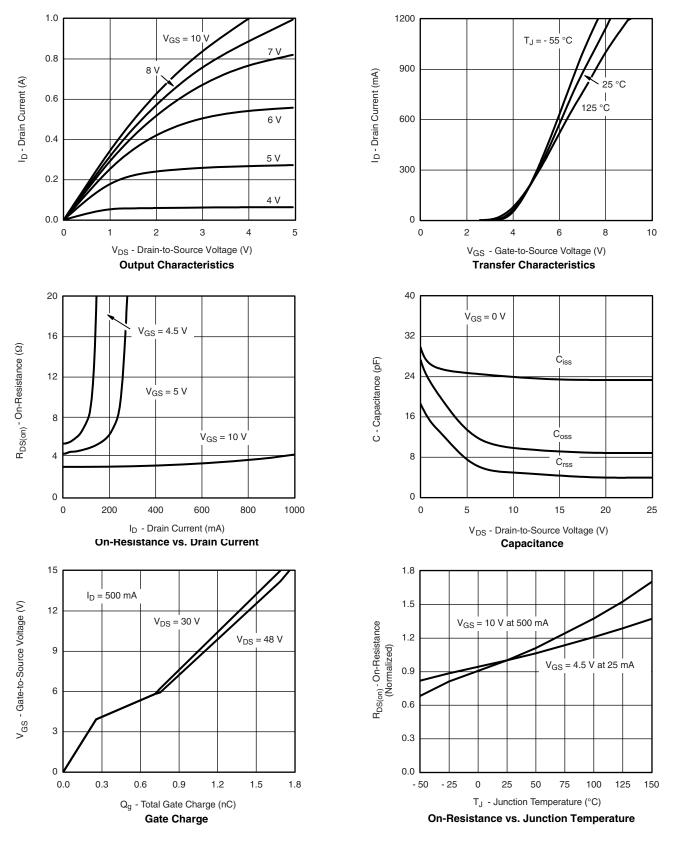
Notes:

- a. Pulse test: PW \leq 300 μs duty cycle \leq 2 %.
- b. Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

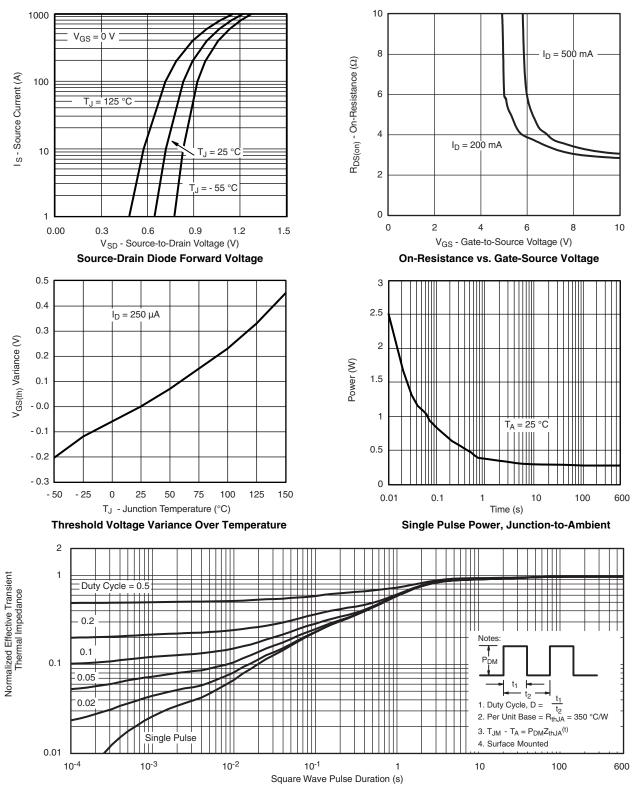


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





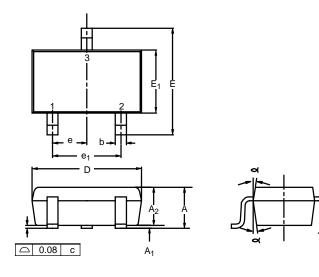
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient



SC-70: 3-LEADS

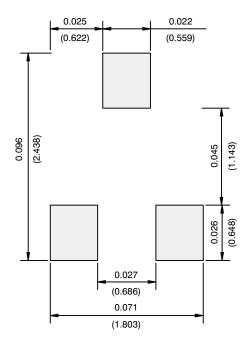


	MILLIMETERS			INCHES		
Dim	Min	Nom	Max	Min	Nom	Max
Α	0.90	-	1.10	0.035	-	0.043
A ₁	-	-	0.10	-	_	0.004
A ₂	0.80	-	1.00	0.031	_	0.039
b	0.25	-	0.40	0.010	_	0.016
С	0.10	-	0.25	0.004	_	0.010
D	1.80	2.00	2.20	0.071	0.079	0.087
Е	1.80	2.10	2.40	0.071	0.083	0.094
E ₁	1.15	1.25	1.35	0.045	0.049	0.053
е	0.65BSC				0.026BSC	;
e ₁	1.20	1.30	1.40	0.047	0.051	0.055
L	0.10	0.20	0.30	0.004	0.008	0.012
a	7°Nom			7°Nom		
Ĺ	0.10	0.20	0.30		0.008	

ECN: S-03946—Rev. C, 09-Jul-01 DWG: 5549



RECOMMENDED MINIMUM PADS FOR SC-70: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)



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